NSN 5961-01-337-5003

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-337-5003 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.250 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.105 inches **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Power Rating Per Characteristic:** 5.5 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig: A110a0